


PRODUCT / PROCESS CHANGE NOTIFICATION

1. PCN basic data

| | |
|----------------------|---|
| 1.1 Company |  STMicroelectronics International N.V |
| 1.2 PCN No. | MDG/23/14224 |
| 1.3 Title of PCN | ASE KaoHsiung (Taiwan) LQFP 100 14x14 package copper palladium bonding wire introduction on STM32H74x, STM32H75x, STM32G47x and STM32G48x listed products |
| 1.4 Product Category | STM32G47x, STM32G48x, STM32H74x, STM32H75x |
| 1.5 Issue date | 2023-09-07 |

2. PCN Team

| | |
|---------------------------|----------------------------|
| 2.1 Contact supplier | |
| 2.1.1 Name | ROBERTSON HEATHER |
| 2.1.2 Phone | +1 8475853058 |
| 2.1.3 Email | heather.robertson@st.com |
| 2.2 Change responsibility | |
| 2.2.1 Product Manager | Ricardo Antonio DE SA EARP |
| 2.1.2 Marketing Manager | Veronique BARLATIER |
| 2.1.3 Quality Manager | Pascal NARCHE |

3. Change

| | | |
|--------------|---|----------------------------|
| 3.1 Category | 3.2 Type of change | 3.3 Manufacturing Location |
| Transfer | Line transfer for a full process or process brick (process step, control plan, recipes) from one site to another site: Assembly site (SOP 2617) | ASE Kaohsiung (TAIWAN) |

4. Description of change

| | | |
|---|--|---|
| | Old | New |
| 4.1 Description | Back-end source: - AMKOR ATP (Philippines) gold wire | Back-end source: - AMKOR ATP (Philippines) gold wire - ASE KaoHsiung (Taiwan) copper palladium wire - additional source |
| 4.2 Anticipated Impact on form,fit, function, quality, reliability or processability? | no impact on product Form, Fit, Function. Package darkness might change depending on molding compound. Ball1 identifier remain in the same corner but might slightly change in terms of form and positioning. Marking position and size could be different upon assembly site, without any loss of information. | |

5. Reason / motivation for change

| | |
|----------------------|--|
| 5.1 Motivation | Due to the success on the market of STM32 devices, ST Microcontrollers Division decided to qualify an additional back-end site to maintain state of the art service level to our customers thanks to extra capacity. |
| 5.2 Customer Benefit | SERVICE CONTINUITY |

6. Marking of parts / traceability of change

| | |
|-----------------|--|
| 6.1 Description | Change is visible through assembly traceability plant, in the marking: - "7B" for AMKOR ATP Philippines - "AA" for ASE Kaohsiung Taiwan Please refer to PCN 14224 – Additional information attached document. |
|-----------------|--|

7. Timing / schedule

| | |
|-------------------------------------|--------------|
| 7.1 Date of qualification results | 2023-09-25 |
| 7.2 Intended start of delivery | 2023-10-05 |
| 7.3 Qualification sample available? | Upon Request |

| 8. Qualification / Validation | | | |
|--|---|------------|------------|
| 8.1 Description | 14224 MDG-GPM-RER2304-PCN13841 PCN14224 V2-ASE LQFP7x7 to 20x20 Copper Palladium wire-Reliability evaluation report.pdf | | |
| 8.2 Qualification report and qualification results | Available (see attachment) | Issue Date | 2023-09-07 |

| 9. Attachments (additional documentations) |
|--|
| 14224 Public product.pdf 14224 MDG-GPM-RER2304-PCN13841 PCN14224 V2-ASE LQFP7x7 to 20x20 Copper Palladium wire-Reliability evaluation report.pdf 14224 PCN14224_Additional information.pdf |

| 10. Affected parts | | |
|-------------------------|-------------------------|--------------------------|
| 10. 1 Current | | 10.2 New (if applicable) |
| 10.1.1 Customer Part No | 10.1.2 Supplier Part No | 10.1.2 Supplier Part No |
| | STM32G473VBT6 | |
| | STM32G473VCT3 | |
| | STM32G473VCT6 | |
| | STM32G473VET3 | |
| | STM32G473VET6 | |
| | STM32G474VBT6 | |
| | STM32G474VET3 | |
| | STM32G474VET6 | |
| | STM32G474VET6TR | |
| | STM32G483VET6 | |
| | STM32G484VET6 | |
| | STM32H742VGT6 | |
| | STM32H742VIT6 | |
| | STM32H743VGT6 | |
| | STM32H743VIT6 | |
| | STM32H743VIT6TR | |
| | STM32H750VBT6 | |
| | STM32H750VBT6TR | |
| | STM32H753VIT6 | |

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Reliability Evaluation Report

MDG-GPM-RER2304

ASEKH LQFP7x7 to LQFP20x20 Copper Palladium wire

| General Information | |
|---------------------|---|
| Commercial Product | STM32L433VCT6 STM32H723ZGT6 STM32F427VIT6 STM32F217ZGT6 STM32L552VET6 STM32F767ZIT6 STM32G030C8T6 |
| Product Line | 435X66 483X66 419X66 411X66 472X66 451X66 466X66 |
| Die revision | 435 cut1.1 483 cut 1.1 419 cut 2.2 411 cut 2.4 472 cut 2.1 451 cut 1.1 466 cut 1.2 |
| Product Description | STM32L4 STM32H7 STM32F4 STM32F2 STM32L5 STM32F7 STM32G0 |
| Package | LQFP 100 14x14x1.4 LQFP 144 20X20X1.4 LQFP 48 7x7x1.4 |
| Silicon Technology | TN090 CMOSM40 CMOSM10 |
| Division | MDG-GPM |

| Traceability | |
|-----------------|--------------------------|
| Diffusion Plant | TSMC Fab14 / Crolles 300 |
| Assembly Plant | ASEKH - TAIWAN |

| Reliability Assessment | |
|------------------------|---|
| Pass | X |
| Fail | |

Reliability Evaluation Report

| Release | Date | Author | Function |
|---------|--------------|-------------|------------|
| 1.0 | 12/06/2023 | Gabin BOSCO | GPM BE Q&R |
| 2.0 | Sept. 5 2023 | Gabin BOSCO | GPM BE Q&R |

Approved by:

| Approval list V1.0 | | | |
|-----------------------------|--------------------------|----------|--------------|
| Name | Function | Location | Date |
| Berengere ROUTIER-SCAPPUCCI | GPM BE Q&R Manager | ROUSSET | 16/06/2023 |
| Pascal NARCHE | Subgroup Quality Manager | ROUSSET | 19/06/2023 |
| Approval list V2.0 | | | |
| Berengere ROUTIER-SCAPPUCCI | GPM BE Q&R Manager | ROUSSET | Sept. 5 2023 |

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RELIABILITY EVALUATION OVERVIEW

• OBJECTIVE

The aim of this report is to present the reliability evaluation performed for the qualification of ASEKH (Taiwan) LQFP7x7/LQFP10x10/LQFP14x14/LQFP20x20 with copper-palladium wires on M10 TSMC/Crolles, M40/E40 Crolles and N90 TSMC.

PCN13841 changes are described here below:

| | Existing back-end line | Added back-end line |
|----------------------------|------------------------|---------------------|
| Assembly site | ASE KaoHsiung (Taiwan) | |
| Wire | Gold 0.8mil | CuPd 0.8mil |
| GLUE | Sumitomo CRM 1076WA | HITACHI EN4900G(1) |
| Marking composition | Without 2D | With 2D marking |

PCN14224 changes are described here below:

| | Existing back-end line | | Added back-end line |
|----------------------------|-------------------------|-------------------------|---|
| Assembly site | AMKOR ATP (Philippines) | | ASE KaoHsiung (Taiwan) |
| Products family | STM32H74x, STM32H75x | STM32G47x, STM32G48x | STM32H74x, STM32G47x, STM32H75x, STM32G48x |
| GLUE | Evertch AP4200 | Sumitomo CRM 1076YB | HITACHI EN4900G(1) |
| Resin | SUMITOMO EME-G631SHQ | Sumitomo EME-G631HQ | SUMITOMO EME-G631SH |
| Wire | Gold 0.8mil | | CuPd 0.8mil |
| Marking composition | Without 2D | | With 2D marking |

⁽¹⁾Sumitomo CRM 1076WA and HITACHI EN4900G glues were used during qualification phase however production will be on HITACHI EN4900G.

• CONCLUSION

All reliability tests have been completed with positive results. Neither functional nor parametric rejects were detected at final electrical testing.

Package oriented tests have not put in evidence any criticality. Physical analysis performed on samples submitted to tests has not put in evidence any issue. ESD CDM are in accordance with ST spec.

Based on the overall results obtained, products below have positively passed reliability evaluation:

| Line code | Commercial product | Diff plant | Assy plant |
|-----------|--------------------|-------------|----------------|
| 435x66 | STM32L433VCT6 | TSMC FAB14 | ASEKH (TAIWAN) |
| 483x66 | STM32H723ZGT6 | Crolles 300 | |
| 419x66 | STM32F427VIT6 | TSMC FAB14 | |
| 411x66 | STM32F217ZGT6 | Crolles 300 | |
| 472x66 | STM32L552VET6 | TSMC FAB14 | |
| 451x66 | STM32F767ZIT6 | Crolles 300 | |
| 466x66 | STM32G030C8T6 | TSMC FAB14 | |

All reliability tests are completed with good results for Finished Goods diffused in M10 TSMC/Crolles, M40/E40 Crolles and N90 TSMC and assembled in LQFP7x7 to LQFP20x20 at ASEKH (Taiwan) in copper-palladium wire.

Refer to Section 3.0 for reliability test results.

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1. RELIABILITY STRATEGY

Reliability trials performed as part of this reliability evaluation are in agreement with ST 0061692 specification, in full compliancy with the JESD-47 international standard.

For details on test conditions, generic data used and specifications references, refer to test results summary in section 3.

2. PRODUCT OR TEST VEHICLE CHARACTERISTICS

2.1. Generalities

| Package line | Partial rawline code | Number of lots |
|--------------------|----------------------|----------------|
| LQFP 100 14x14x1.4 | 1L*435 | 1 |
| | 1L*419 | 1 |
| | 1L*472 | 1 |
| LQFP 144 20X20X1.4 | 1A*483 | 1 |
| | 1A*411 | 1 |
| | 1A*451 | 1 |
| LQFP 48 7x7x1.4 | 5B*466 | 1 |

2.2. Traceability

2.2.1. Wafer Fab Information

Die 435

| Wafer Fab Information | | | |
|--|---------------------------------|------------------|-----------|
| FAB1 | | | |
| Wafer fab name / location | TSMC Fab14 / Taiwan | | |
| Wafer diameter (inches) | 12 | | |
| Wafer thickness (µm) | 775±25 | | |
| Silicon process technology | TN090 | | |
| Number of masks | 45 | | |
| Die finishing front side (passivation) materials / thickness | PSG+NITRIDE / 1,75µm | | |
| Die finishing back side Materials | RAW SILICON | | |
| Die area (Stepping die size) | 10.045 mm² (3176.4µm, 3162.4µm) | | |
| Die pad size | Geometry | | Open(X,Y) |
| | Rectangular | | 123,59 µm |
| Sawing street width (X,Y) (µm) | 80,80 | | |
| Metal levels/Materials/Thicknesses | Wire bond pad metal | Composition | Thickness |
| | 1 | TaN/Ta/CuSeed/Cu | 0.24 µm |
| | 2 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 3 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 4 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 5 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 6 | TaN/Ta/CuSeed/Cu | 0.85 µm |
| | 7 | AlCu | 1.45 µm |

Reliability Evaluation Report

Die 483

| Wafer Fab Information | | | |
|--|----------------------------|------------------|-----------|
| FAB1 | | | |
| Wafer fab name / location | Crolles 300 / France | | |
| Wafer diameter (inches) | 12 | | |
| Wafer thickness (µm) | 775±25 | | |
| Silicon process technology | CMOSM40 | | |
| Number of masks | 51 | | |
| Die finishing front side (passivation) materials / thickness | PSG+NITRIDE / 1,75µm | | |
| Die finishing back side Materials | RAW SILICON | | |
| Die area (Stepping die size) | 15.67 mm² (3753µm, 4175µm) | | |
| Die pad size | Geometry | Open(X,Y) | |
| | Rectangular | 54.9,54.4 µm | |
| Sawing street width (X,Y) (µm) | 80,80 | | |
| Metal levels/Materials/Thicknesses | Wire bond pad metal | Composition | Thickness |
| | 1 | TaN/Ta/CuSeed/Cu | 0.13 µm |
| | 2 | TaN/Ta/CuSeed/Cu | 0.14 µm |
| | 3 | TaN/Ta/CuSeed/Cu | 0.14 µm |
| | 4 | TaN/Ta/CuSeed/Cu | 0.14 µm |
| | 5 | TaN/Ta/CuSeed/Cu | 0.14 µm |
| | 6 | TaN/Ta/CuSeed/Cu | 0.85 µm |
| | 7 | TaN/Ta/CuSeed/Cu | 0.85 µm |
| | 8 | Ta/TaN/AlCu | 1.525 µm |
| | | | |

Reliability Evaluation Report

Die 411

| Wafer Fab Information | | | |
|--|---------------------------|---------------|-----------|
| FAB1 | | | |
| Wafer fab name / location | Crolles 300 / France | | |
| Wafer diameter (inches) | 12 | | |
| Wafer thickness (µm) | 775±25 | | |
| Silicon process technology | CMOSM10 | | |
| Number of masks | 42 | | |
| Die finishing front side (passivation) materials / thickness | PSG+NITRIDE / 1,75µm | | |
| Die finishing back side Materials | RAW SILICON | | |
| Die area (Stepping die size) | 14.71mm² (4006µm, 3674µm) | | |
| Die pad size | Geometry | | Open(X,Y) |
| | Rectangular | | 59,123 µm |
| | Rectangular | | 63,73 µm |
| Sawing street width (X,Y) (µm) | 80,80 | | |
| Metal levels/Materials/Thicknesses | Wire bond pad metal | Composition | Thickness |
| | 1 | TaN/CuSeed/Cu | 0.24 µm |
| | 2 | TaN/CuSeed/Cu | 0.33 µm |
| | 3 | TaN/CuSeed/Cu | 0.33 µm |
| | 4 | TaN/CuSeed/Cu | 0.33 µm |
| | 5 | TaN/CuSeed/Cu | 0.33 µm |
| | 6 | TaN/CuSeed/Cu | 0.85 µm |
| | 7 | AlCu/TinArc | 1.45 µm |

Reliability Evaluation Report

Die 419

| Wafer Fab Information | | | |
|--|----------------------------|------------------|-----------|
| FAB1 | | | |
| Wafer fab name / location | TSMC Fab14 / Taiwan | | |
| Wafer diameter (inches) | 12 | | |
| Wafer thickness (μm) | 775±25 | | |
| Silicon process technology | CMOSM10 | | |
| Number of masks | 44 | | |
| Die finishing front side (passivation) materials / thickness | USG + NITRIDE / 1.1μm | | |
| Die finishing back side Materials | RAW SILICON | | |
| Die area (Stepping die size) | 25.43 mm² (5582μm, 4556μm) | | |
| Die pad size | Geometry | | Open(X,Y) |
| | Rectangular | | 59,123 μm |
| Sawing street width (X,Y) (μm) | 80,80 | | |
| Metal levels/Materials/Thicknesses | Wire bond pad metal | Composition | Thickness |
| | 1 | TaN/Ta/CuSeed/Cu | 0.22 μm |
| | 2 | TaN/Ta/CuSeed/Cu | 0.28 μm |
| | 3 | TaN/Ta/CuSeed/Cu | 0.28 μm |
| | 4 | TaN/Ta/CuSeed/Cu | 0.28 μm |
| | 5 | TaN/Ta/CuSeed/Cu | 0.28 μm |
| | 6 | Ta/TaN/AlCu | 0.73 μm |
| | 7 | AlCu | 1.2 μm |

Reliability Evaluation Report

Die 472

| Wafer Fab Information | | | |
|--|-----------------------------|------------------|-----------|
| FAB1 | | | |
| Wafer fab name / location | TSMC Fab14 / Taiwan | | |
| Wafer diameter (inches) | 12 | | |
| Wafer thickness (µm) | 775±25 | | |
| Silicon process technology | TN090 | | |
| Number of masks | 45 | | |
| Die finishing front side (passivation) materials / thickness | USG + NITRIDE / 1,75µm | | |
| Die finishing back side Materials | RAW SILICON | | |
| Die area (Stepping die size) | 17.999 mm² (4099.2, 4391.0) | | |
| Die pad size | Geometry | | Open(X,Y) |
| | Rectangular | | 123,59 µm |
| Sawing street width (X,Y) (µm) | 80,80 | | |
| Metal levels/Materials/Thicknesses | Wire bond pad metal | Composition | Thickness |
| | 1 | TaN/Ta/CuSeed/Cu | 0.24 µm |
| | 2 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 3 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 4 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 5 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 6 | TaN/Ta/CuSeed/Cu | 0.85 µm |
| | 7 | AlCu | 1.45 µm |

Reliability Evaluation Report

Die 451

| Wafer Fab Information | | | |
|--|------------------------|---------------|-----------|
| FAB1 | | | |
| Wafer fab name / location | Crolles 300 / France | | |
| Wafer diameter (inches) | 12 | | |
| Wafer thickness (μm) | 775±25 | | |
| Silicon process technology | CMOSM10 | | |
| Number of masks | 43 | | |
| Die finishing front side (passivation) materials / thickness | PSG + NITRIDE / 1.1μm | | |
| Die finishing back side Materials | RAW SILICON | | |
| Die area (Stepping die size) | 34.15 mm² (6130, 5572) | | |
| Die pad size | Geometry | | Open(X,Y) |
| | Rectangular | | 59,123 μm |
| Sawing street width (X,Y) (μm) | 80,80 | | |
| Metal levels/Materials/Thicknesses | Wire bond pad metal | Composition | Thickness |
| | 1 | TaN/CuSeed/Cu | 0.24 μm |
| | 2 | TaN/CuSeed/Cu | 0.33 μm |
| | 3 | TaN/CuSeed/Cu | 0.33 μm |
| | 4 | TaN/CuSeed/Cu | 0.33 μm |
| | 5 | TaN/CuSeed/Cu | 0.33 μm |
| | 6 | TaN/CuSeed/Cu | 0.85 μm |
| | 7 | AlCu/TinArc | 1.45 μm |

Reliability Evaluation Report

Die 466

| Wafer Fab Information | | | |
|--|-----------------------------|------------------|-----------|
| FAB1 | | | |
| Wafer fab name / location | TSMC Fab14 / Taiwan | | |
| Wafer diameter (inches) | 12 | | |
| Wafer thickness (µm) | 775±25 | | |
| Silicon process technology | TN090 | | |
| Number of masks | 45 | | |
| Die finishing front side (passivation) materials / thickness | USG + NITRIDE / 1.1µm | | |
| Die finishing back side Materials | RAW SILICON | | |
| Die area (Stepping die size) | 4.0921 mm² (1889.6, 2165.6) | | |
| Die pad size | Geometry | | Open(X,Y) |
| | Rectangular | | 65,59 µm |
| | Rectangular | | 123,59 µm |
| Sawing street width (X,Y) (µm) | 80,80 | | |
| Metal levels/Materials/Thicknesses | Wire bond pad metal | Composition | Thickness |
| | 1 | TaN/Ta/CuSeed/Cu | 0.24 µm |
| | 2 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 3 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 4 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 5 | TaN/Ta/CuSeed/Cu | 0.31 µm |
| | 6 | TaN/Ta/CuSeed/Cu | 0.85 µm |
| | 7 | AlCu | 1.45 µm |

2.2.2.Assembly Information

| Assembly Information | | | |
|--|--|-----|-----------------|
| Package: LQFP 100 14x14x1.4 1 | 435 | 419 | 472 |
| Assembly plant name / location | ASE Taiwan | | |
| Pitch (mm) | 0,5 | | |
| Die thickness after back-grinding (µm) | 375±25 | | |
| Die sawing method | Laser groove + mechanical sawing | | |
| Bill of Material elements | | | |
| Lead frame/ material/ reference | LF# A25516 LQ14 100L Pure Tin C7025 6.6sq Slot | | |
| Lead frame finishing (material/thickness) | Pure Tin (e3): Tolerance 7 to 20µm | | |
| Die attach material/ glue /supplier | GLUE SUMITOMO EPOXY CRM 1076WA | | HITACHI EN4900G |
| Wire bonding material/diameter | Wire CuPd 0.8 mils | | |
| Molding compound material/supplier/reference | MOLDING RESIN SUMITOMO EME-G631SH | | |
| Package Moisture Sensitivity Level (JEDEC J-STD020D) | 3 | | |

| Assembly Information | | | |
|--|---|-----|-----------------|
| Package 2: LQFP 144 20X20X1.4 2 | 483 | 411 | 451 |
| Assembly plant name / location | ASE Taiwan | | |
| Pitch (mm) | 0.5 | | |
| Die thickness after back-grinding (µm) | 375±25 | | |
| Die sawing method | Laser groove + mechanical sawing | | |
| Bill of Material elements | | | |
| Lead frame/material/reference | LF# A25582 LQ20 144L Pure Tin C7025 6.6sq | | |
| Lead frame finishing (material/thickness) | Pure Tin (e3): Tolerance 7 to 20µm | | |
| Die attach material/glue/supplier | GLUE SUMITOMO EPOXY CRM 1076WA | | HITACHI EN4900G |
| Wire bonding material/diameter | Wire CuPd 0.8 mils | | |
| Molding compound material/supplier/reference | MOLDING RESIN SUMITOMO EME-G631SH | | |
| Package Moisture Sensitivity Level (JEDEC J-STD020D) | 3 | | |

Reliability Evaluation Report

| Assembly Information | |
|--|--|
| Package 3:LQFP 48 7x7x1.4 1 | |
| Assembly plant name / location | ASE Taiwan |
| Pitch (mm) | 0.5 |
| Die thickness after back-grinding (μm) | 375±25 |
| Die sawing method | |
| Bill of Material elements | |
| Lead frame/material/reference | LF# A24950 LQ48L Pur tin C7025 4.092sq |
| Lead frame finishing (material/thickness) | Pure Tin (e3): Tolerance 7 to 20μm |
| Die attach material/glue/supplier | HITACHI EN4900G |
| Wire bonding material/diameter | Wire CuPd 0.8 mils |
| Molding compound material/supplier/reference | MOLDING RESIN SUMITOMO EME-G631SH |
| Package Moisture Sensitivity Level (JEDEC J-STD020D) | 3 |

2.2.3. Reliability testing information

| Reliability Testing Information | |
|--|--|
| Reliability laboratory name / location | Grenoble Rel Lab, Shenzhen BE Lab, Rousset MDG Rel Lab |

Note: ST is ISO 9001 certified. This induces certification of all internal and subcontractor labs. ST certification document can be downloaded under the following link: http://www.st.com/content/st_com/en/support/quality-and-reliability/certifications.html

Reliability Evaluation Report

3. TEST RESULTS SUMMARY

3.1. Lot information

| Lot # | Diffusion Lot / Wafer ID | Die Revision (Cut) | Assy Lot / Trace Code | Raw Line | Package |
|-------|--------------------------|--------------------|-----------------------|--------------|----------------------|
| Lot 1 | 9R113962 | Cut1.1 | AA136031 | 211L*435CSXZ | LQFP 100 14x14x1.4 1 |
| Lot 2 | 3R31C302 | Cut 1.1 | AA143030 | 221A*483CSXZ | LQFP 144 20X20X1.4 2 |
| Lot 3 | VQ112465 | Cut 2.4 | AA136033 | 201A*411CSX2 | LQFP 144 20X20X1.4 2 |
| Lot 4 | 9R121544 | Cut 2.2 | AA136032 | 201L*419CSX5 | LQFP 100 14x14x1.4 1 |
| Lot 5 | 9R23159 | Cut 2.1 | AA248173 | 211L*472QCXZ | LQFP 100 14x14x1.4 1 |
| Lot 6 | Q229850 | Cut 1.1 | AA306008 | 201A*451QCXZ | LQFP 144 20X20X1.4 2 |
| Lot 7 | 9R230180 | Cut 1.2 | AA249007 | 235B*466QCXY | LQFP 48 7x7x1.4 1 |

3.2. Test results summary

ACCELERATED ENVIRONMENT STRESS TESTS

| Test code | Stress method | Stress Conditions | Lots Qty | S.S. | Total | Results/Lot Fail/S.S. | Comments:(N/A =Not Applicable) |
|-----------|-------------------------------------|---|----------|------|-------|---|--------------------------------|
| PC | JSTD 020 JESD 22-A113 7191395 | 24h bake@125°C, MSL3 (192h/30°C/60%RH) 3x Reflow simulation Peak Reflow Temp= 260°C | 7 | 308 | 2156 | Lot 1: 0/308 Lot 5: 0/308 Lot 2: 0/308 Lot 6: 0/308 Lot 3: 0/308 Lot 7: 0/308 Lot 4: 0/308 | NA |
| HTSL | JESD22-A103 | Ta= 150°C Duration= 1000hrs <input checked="" type="checkbox"/> After PC | 7 | 77 | 539 | Lot 1: 0/77 Lot 5: 0/77 Lot 2: 0/77 Lot 6: 0/77 Lot 3: 0/77 Lot 7: 0/77 Lot 4: 0/77 | NA |
| TC | JESD22-A104 | Ta= -65/150°C Cyc= 500 <input checked="" type="checkbox"/> After PC | 7 | 77 | 539 | Lot 1: 0/77 Lot 5: 0/77 Lot 2: 0/77 Lot 6: 0/77 Lot 3: 0/77 Lot 7: 0/77 Lot 4: 0/77 | NA |
| THB | JESD22-A101 | Ta=85°C/85%RH VDD=3v6 Duration= 1000hrs <input checked="" type="checkbox"/> After PC | 7 | 77 | 539 | Lot 1: 0/77 Lot 5: 0/77 Lot 2: 0/77 Lot 6: 0/77 Lot 3: 0/77 Lot 7: 0/77 Lot 4: 0/77 | NA |
| UHASt | JESD22-A118 | Ta=130°C ,85% RH, 2 Atm Duration= 96hrs <input checked="" type="checkbox"/> After PC | 4 | 77 | 539 | Lot 1: 0/77 Lot 5: 0/77 Lot 2: 0/77 Lot 6: 0/77 Lot 3: 0/77 Lot 7: 0/77 Lot 4: 0/77 | NA |

Reliability Evaluation Report

ELECTRICAL TEST VERIFICATION

| Test code | Stress method | Stress Conditions | Lots Qty | S.S. | Total | Results/Lot Fail/S.S. | Comments:(N/A =Not Applicable) |
|-----------|---------------|--|----------|------|-------|---|--------------------------------|
| CDM | JEDEC JS-002 | Voltage=500V for 411/466 Voltage=250V for 435/483/419/472/451 | 7 | 3 | 21 | Lot 1: 0/3 Lot 5: 0/3 Lot 2: 0/3 Lot 6: 0/3 Lot 3: 0/3 Lot 7: 0/3 Lot 4: 0/3 | NA |

PACKAGE ASSEMBLY INTEGRITY TESTS

| Test code | Stress method | Stress Conditions | Lots Qty | S.S. | Total | Results/Lot Fail/S.S. | Comments:(N/A =Not Applicable) |
|-----------|--|----------------------------|----------|------|-------|---|---|
| CA | Construction analysis including -Wire bond shear -Wire bond pull | ST internal specifications | 7 | 50 | 350 | Lot 1: 0/50 Lot 2: 0/50 Lot 3: 0/50 Lot 4: 0/50 Lot 5: 0/50 Lot 6: 0/50 Lot 7: 0/50 | SHZ-CA_21_00299 SHZ-CA_22_00003 SHZ-CA_21_00351 SHZ-CA_21_00298 SHZ-CA_23_00132 SHZ-CA_23_00275 SHZ-CA_23_00075 |

Note: Test method revision reference is the one active at the date of reliability trial execution.

4. APPLICABLE AND REFERENCE DOCUMENTS

| Reference | Short description |
|--------------|---|
| JESD47 | Stress-Test-Driven Qualification of Integrated Circuits |
| SOP2.4.4 | Record Management Procedure |
| SOP2.6.2 | Internal Change Management |
| SOP2.6.7 | Finished Good Maturity Management |
| SOP2.6.9 | Package & Process Maturity Management in BE |
| SOP2.6.11 | Program Management for Product Development |
| SOP2.6.17 | Management of Manufacturing Transfers |
| SOP2.6.19 | Front-End Technology Platform Development and Qualification |
| DMS 0061692 | Reliability Tests and Criteria for Product Qualification |
| JEDEC JS-002 | Electrostatic discharge (ESD) sensitivity testing charge device model (CDM) |
| JESD 22-A103 | High Temperature Storage Life |
| J-STD-020 | Moisture/reflow sensitivity classification for non-hermetic solid state surface mount devices |
| JESD22-A113 | Preconditioning of non-hermetic surface mount devices prior to reliability testing |
| JESD22-A118 | Unbiased Highly Accelerated temperature & humidity Stress Test |
| JESD22-A104 | Temperature cycling |
| JESD22-A101 | Temperature Humidity Bias |

5. GLOSSARY

| | |
|----------------|--|
| ESD-CDM | Electrostatic Discharge - Charged device model |
| CA | Construction analysis |
| HTSL | High Temperature Storage Life |
| PC | Preconditioning |
| TC | Temperature Cycling |
| THB | Temperature Humidity Bias |
| UHA | Unbiased HAST (Highly Accelerated Stress Test) |
| DMS | ST Advanced Documentation Controlled system/ Documentation Management system |

6. REVISION HISTORY

| Release | Author | Content description | Approval list | | | |
|---------|-------------|---------------------|--------------------------|----------|-----------------------------|--------------|
| | | | Function | Location | Name | Date |
| 1.0 | Gabin BOSCO | Initial release | Subgroup Quality Manager | ROUSSET | Pascal NARCHE | 19/06/2023 |
| | | | GPM BE Q&R Manager | ROUSSET | Berengere ROUTIER-SCAPPUCCI | 16/06/2023 |
| 2.0 | Gabin BOSCO | Added PCN14224 | GPM BE Q&R Manager | ROUSSET | Berengere ROUTIER-SCAPPUCCI | Sept. 5 2023 |

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PRODUCT/PROCESS CHANGE NOTIFICATION

PCN14224 – Additional information

ASE KaoHsiung (Taiwan) LQFP 100 14x14 package copper palladium bonding wire introduction on STM32H74x, STM32H75x, STM32G47x and STM32G48x listed products

MDG – General Purpose Microcontrollers Division (GPM)

What are the changes?

Changes described in table below:

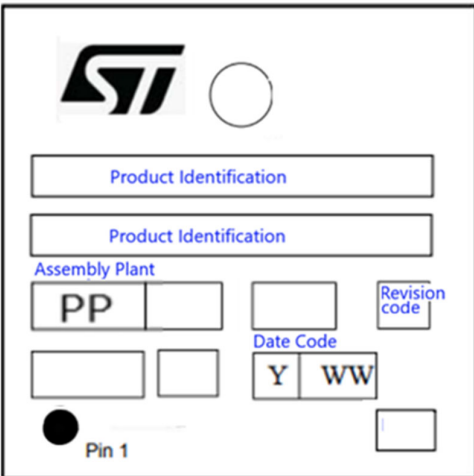
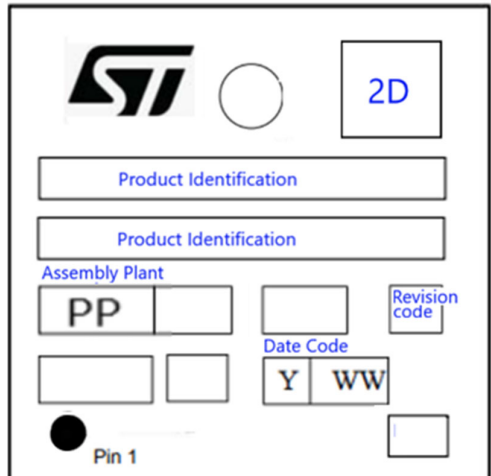
| | Existing back-end line | | Added back-end line |
|---------------------|-------------------------|-------------------------|---|
| Assembly site | AMKOR ATP (Philippines) | | ASE KaoHsiung (Taiwan) |
| Products family | STM32H74x, STM32H75x | STM32G47x, STM32G48x | STM32H74x, STM32G47x, STM32H75x, STM32G48x |
| Glue | Evertch AP4200 | Sumitomo CRM 1076YB | Hitachi EN4900G |
| Resin (1) | Sumitomo EME-G631SHQ | Sumitomo EME-G631HQ | Sumitomo EME-G631SH |
| Wire | Gold 0.8mil | | CuPd 0.8mil |
| Marking composition | Without 2D | | With 2D Marking |

(1) Package darkness changes depending on molding compound.

How can the change be seen?

Package top view Marking will display the 2D marking

Examples in below table

| | Existing line | Added Line |
|---------|--|--|
| LQFP100 |  <p>The diagram shows the existing marking layout for an LQFP100 package. It includes the ST logo, a circle, three 'Product Identification' boxes, an 'Assembly Plant' box with 'PP', a 'Date Code' box with 'Y' and 'WW', a 'Revision code' box, and a 'Pin 1' indicator.</p> |  <p>The diagram shows the updated marking layout for an LQFP100 package, including a '2D' marking box in the top right corner. All other markings (ST logo, circle, Product Identification boxes, Assembly Plant, Date Code, Revision code, and Pin 1 indicator) remain the same as in the existing line.</p> |

Y WW code indicates Year Week (manufacturing date)

PP code indicates assembly traceability plant code.

| Existing | | Additional | |
|----------|-----------------------|------------|----------------------|
| PP code | Fab | PP code | Fab |
| 7B | Amkor ATP Philippines | AA | ASE Kaohsiung Taiwan |

Please refer to product [DataSheet](#) or Technical Note **TN1433** for package marking details.



life.augmented

How to order samples?

For all samples request linked to this PCN, please:

- place a **Non-standard** sample order (choose Sample Non Std Type from pull down menu).
- insert the PCN number "**PCN14224**" into the NPO Electronic Sheet/**Regional Sheet**.
- request sample(s) through Notice tool, indicating a single Commercial Product for each request.

Partial Ship: 01 Price Pol: 05 Status: 01 Canc:

%: 0 Sample Type: Sample Non Std Type

Closing Type: Sample Std Type
Sample Non Std Type
Sample Non Std w Spl Tests

Lab Sheet:

SO | NPO Sample

Header

SO Nr: 8018502433 Customer: 99770200 01 ST-TOKYO SO Type: 30 Sample Order Cost Center: JT3129 SAMPLES /SALES J

PO Nr: Carrier Code: 0001 Price Policy: 05 Currency: 02 U.S. DOLLAR Req Name:

Notes: Status: 01 All items pending, n Issuing Date: 25-JUN-2018 Ord Val: 0.0000 Sample Req Date: 25-Jun-2018

| Sch I Nr | PO I. Nr. | Finished Good | Comm Qty | Open Qty | Plant Open Qty | Reqd Qty | Unit Price | RD | CD | EDD | St |
|----------|-----------|---------------|----------|----------|----------------|----------|------------|-----------|-----------|-----------|----|
| 1.1.10 | 000001 | STM32F429NIH6 | 30 | 30 | 30 | 30 | 0.0000 | 25-Jun-18 | 01-Mar-53 | 01-Mar-53 | 01 |

Final Cust: PO Item: 000001 Comm Prod: STM32F429NIH6 Qty: 30 RD: 25-Jun-18 Unit Price: 0.0000 Final Cust: 8800367006 SANSHIN/NPC

Cust Part Nr: Finished Good: Partial Ship: 01 Price Pol: 05 Status: 01 Canc:

Notes: TAM K Pieces: 0 Our Share%: 0 Sample Type: Sample Non Std Type

Project Name: Closing Date: Closing Type:

Regional Sheet: **PCN14224** Lab Sheet:

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PCN Title : ASE KaoHsiung (Taiwan) LQFP 100 14x14 package copper palladium bonding wire introduction on STM32H74x, STM32H75x, STM32G47x and STM32G48x listed products

PCN Reference : MDG/23/14224

Subject : Public Products List

Dear Customer,

Please find below the Standard Public Products List impacted by the change.

| | | |
|-----------------|-----------------|-----------------|
| STM32H742VGT6 | STM32H743VIT6 | STM32H742VIT6TR |
| STM32H753VIT6 | STM32G474VET6 | STM32H750VBT6 |
| STM32G474VBT3TR | STM32G473VCT3TR | STM32G474VCT6 |
| STM32G474VET3TR | STM32H743VGT6 | STM32G474VBT3 |
| STM32H750VBT6TR | STM32G474VET6TR | STM32G484VET6 |
| STM32G483VET3 | STM32G473VCT6TR | STM32G474VBT6 |
| STM32H743VIT6TR | STM32G474VET3 | STM32G473VET6TR |
| STM32H742VGT6TR | STM32H742VIT6 | STM32G483VET6 |
| STM32G473VCT3 | STM32G473VET6 | STM32G473VBT6 |
| STM32G473VET3 | STM32G473VCT6 | |

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